

**CMOD4448**

**SURFACE MOUNT  
HIGH SPEED  
SILICON SWITCHING DIODE**

**ULTRAmini™**



**SOD-523 CASE**



[www.centralsemi.com](http://www.centralsemi.com)

**DESCRIPTION:**

The CENTRAL SEMICONDUCTOR CMOD4448 type is a ultra-high speed silicon switching diode manufactured by the epitaxial planar process, epoxy molded in an ULTRAmini™ surface mount package, designed for high speed switching applications.

**MARKING CODE: 48**

**MAXIMUM RATINGS: ( $T_A=25^\circ\text{C}$ )**

	<b>SYMBOL</b>		<b>UNITS</b>
Continuous Reverse Voltage	$V_R$	75	V
Peak Repetitive Reverse Voltage	$V_{RRM}$	100	V
Continuous Forward Current	$I_F$	250	mA
Peak Repetitive Forward Current	$I_{FRM}$	500	mA
Peak Forward Surge Current, $t_p=1.0\mu\text{s}$	$I_{FSM}$	4.0	A
Peak Forward Surge Current, $t_p=1.0\text{s}$	$I_{FSM}$	1.0	A
Power Dissipation	$P_D$	250	mW
Operating and Storage Junction Temperature	$T_J, T_{stg}$	-65 to +150	$^\circ\text{C}$
Thermal Resistance	$\Theta_{JA}$	500	$^\circ\text{C}/\text{W}$

**ELECTRICAL CHARACTERISTICS: ( $T_A=25^\circ\text{C}$  unless otherwise noted)**

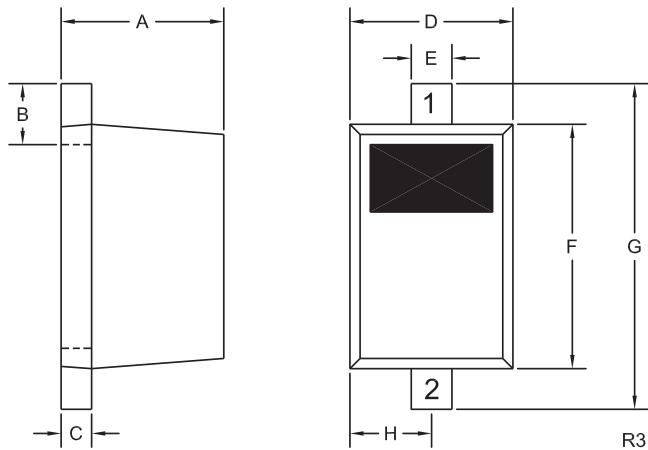
<b>SYMBOL</b>	<b>TEST CONDITIONS</b>	<b>MIN</b>	<b>MAX</b>	<b>UNITS</b>
$I_R$	$V_R=20\text{V}$		25	nA
$BV_R$	$I_R=5.0\mu\text{A}$	75		V
$BV_R$	$I_R=100\mu\text{A}$	100		V
$V_F$	$I_F=5.0\text{mA}$	0.62	0.72	V
$V_F$	$I_F=100\text{mA}$		1.0	V
$C_T$	$V_R=0, f=1.0\text{MHz}$		4.0	pF
$t_{rr}$	$I_R=I_F=10\text{mA}, I_{rr}=1.0\text{mA}, R_L=100\Omega$		4.0	ns

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**SOD-523 CASE - MECHANICAL OUTLINE**



**LEAD CODE:**

- 1) Cathode
- 2) Anode

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SYMBOL	DIMENSIONS			
	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.020	0.031	0.50	0.80
B	0.008	0.016	0.20	0.40
C	0.002	0.008	0.05	0.20
D	0.028	0.035	0.70	0.90
E	0.008	0.014	0.20	0.35
F	0.039	0.055	1.00	1.40
G	0.055	0.071	1.40	1.80
H	0.016		0.40	

SOD-523 (REV: R3)

R6 (11-April 2011)